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PATENT ASSIGNMENT COVER SHEET

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EPAS ID: PAT5617532

SUBMISSION TYPE:	NEW ASSIGNMENT
NATURE OF CONVEYANCE:	ASSIGNMENT

CONVEYING PARTY DATA

Name	Execution Date
PEI-HSUN WANG	06/13/2019
CHUN-HSIUNG LIN	07/02/2019
CHIH-HAO WANG	06/20/2019

RECEIVING PARTY DATA

Name:	TAIWAN SEMICONDUCTOR MANUFACTURING CO., LTD.
Street Address:	8, LI-HSIN RD. 6
Internal Address:	HSINCHU SCIENCE PARK
City:	HSINCHU
State/Country:	TAIWAN
Postal Code:	300-78

PROPERTY NUMBERS Total: 1

Property Type	Number
Application Number:	16511176

CORRESPONDENCE DATA

Fax Number: (214)200-0853

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ATTORNEY DOCKET NUMBER:	2018-3050/24061.3857US01
NAME OF SUBMITTER:	DAVID M. O'DELL
SIGNATURE:	/David M. O'Dell/
DATE SIGNED:	07/15/2019

Total Attachments: 4

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Docket No.: P20183050US00/24061.3857US01 Customer No.: 42717

ASSIGNMENT

WHEREAS, we,

(1)	Pei-Hsun Wang	of	Hsinchu,	Taiwan, I	Republic	of China	
(2)	Chun-Hsiung Lin	of	Hsinchu (County, T	'aiwan, F	Republic o	f China
(3)	Chih-Hao Wang	of	Hsinchu C	County, T	aiwan, F	Republic o	f China

have invented certain improvements in

GATE-ALL-AROUND STRUCTURE AND METHODS OF FORMING THE SAME

for which we have executed an application for Letters Patent of the United States of America,

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WHEREAS, we authorize the attorney of record to update this document to include Patent Office information as deemed necessary (i.e., filing date, serial number, etc.);

WHEREAS, Taiwan Semiconductor Manufacturing Co., Ltd., ("TSMC"), 8, Li-Hsin Rd. 6, Hsinchu Science Park, Hsinchu, Taiwan 300-78, Republic of China is desirous of obtaining the entire right, title, and interest in, to and under the said invention and the said application in the United States of America and in any and all countries foreign thereto;

NOW, THEREFORE, for good and valuable consideration, the receipt and sufficiency of which is hereby acknowledged, and other good and valuable consideration, we have sold, assigned, transferred and set over, and by these presents do hereby sell, assign, transfer and set over, unto the said TSMC, its successors, legal representatives, and assigns, the entire right, title, and interest in, to and under the said invention, and the said application, and all divisional, renewal, substitutional, and continuing applications thereof, and all Letters Patent of the United States of America which may be granted thereon and all reissues and extensions thereof, and all applications for Letters Patent which may be filed for said invention in any country or countries foreign to the United States of America, and all extensions, renewals, and reissues thereof, and all prior patents and patent applications from which a filing priority of the above-described patent application may be obtained, including the right to collect past damages; and we hereby authorize and request the Commissioner of Patents of the United States of America, and any official of any country or countries foreign to the United States of America, whose duty it is to issue patents on applications as aforesaid, to issue all Letters Patent for said invention to the said TSMC, its successors, legal representatives and assigns, in accordance with the terms of this instrument.

AND WE HEREBY covenant that we have full right to convey the entire interest herein assigned, and that we have not executed, and will not execute, any agreement in conflict herewith.

AND WE HEREBY further covenant and agree that we will communicate to said TSMC, its successors, legal representatives and assigns, any facts known to us respecting said invention, and testify in any legal proceedings, sign all lawful papers, execute all divisional, renewal, substitutional,

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continuing, and reissue applications, make all rightful declarations and/or oaths and generally do everything possible to aid the said TSMC, its successors, legal representatives and assigns, to obtain and enforce proper patent protection for said invention in all countries.

Inventor Name:	Pei-Hsun Wang	
Residence Address:	8, Li-Hsin Rd. 6 Hsinchu, Taiwan 300-	78, Republic of China
Dated: <u>219,06</u>	<u>. 13</u>	Inventor Signature
Inventor Name:	Chun-Hsiung Lin	
Residence Address:	8B, 143 Keda 2 nd St. Zhubei City, Hsinchu	County, Taiwan, Republic of China
Dated:		Inventor Signature
		mvemor signature
Inventor Name:	Chih-Hao Wang	
Residence Address:	No. 9, Aly. 22, Ln. 80, Baoshan Townchip, H	Songcui Rd. sinchu County 308, Taiwan, Republic of China
Dated: 6/20)	/2019	Chih-Ho Wang
		Inventor Signature



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(2)	Chun-Hsìung Lin	of	Hsinchu County, Taiwan, Republic of China
(3)	Chih-Hao Wang	of	Hsinchu County, Taiwan, Republic of China

have invented certain improvements in

GATE-ALL-AROUND STRUCTURE AND METHODS OF FORMING THE SAME

for which we have executed an application for Letters Patent of the United States of America,

	of even date filed herewith; and	
X	filed on 07-15-2019 and assigned application number 16/511,176;	ınd

WHEREAS, we authorize the attorney of record to update this document to include Patent Office information as deemed necessary (i.e., filing date, serial number, etc.);

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AND WE HEREBY covenant that we have full right to convey the entire interest herein assigned, and that we have not executed, and will not execute, any agreement in conflict herewith.

AND WE HEREBY further covenant and agree that we will communicate to said TSMC, its successors, legal representatives and assigns, any facts known to us respecting said invention, and testify in any legal proceedings, sign all lawful papers, execute all divisional, renewal, substitutional,

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continuing, and reissue applications, make all rightful declarations and/or oaths and generally do everything possible to aid the said TSMC, its successors, legal representatives and assigns, to obtain and enforce proper patent protection for said invention in all countries.

Inventor Name:	Pei-Hsun Wang	
Residence Address:	8, Li-Hsin Rd. 6 Hsinchu, Taiwan 300-78, Repu	blic of China
Dated:		Inventor Signature
Inventor Name:	Chun-Hsiung Lin	
Residence Address:	8B, 143 Keďa 2 nd St. Zhubei City, Hsinchu County, '	Taiwan, Republic of China
Dated: 7/2/>	19	M. G.J. Inventor Signature
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Inventor Name:	Chih-Hao Wang	
Residence Address:	No. 9, Aly. 22, Ln. 80, Songcui Baoshan Townchip, Hsinchu C	i Rd. ounty 308, Taiwan, Republic of China
Dated:		
		Inventor Signature